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74HC594-Q100; 74HCT594-Q100

8-bit shift register with output register

Rev. 2 — 13 June 2016

Product data sheet

1. General description

The 74HC594-Q100; 74HCT594-Q100 is a high-speed Si-gate CMOS device and is pin compatible with Low-Power Schottky TTL (LSTTL).

The 74HC594-Q100; 74HCT594-Q100 is an 8-bit, non-inverting, serial-in, parallel-out shift register that feeds an 8-bit D-type storage register. Separate clocks (SHCP and STCP) and direct overriding clears (SHR and STR) are provided on both the shift and storage registers. A serial output (Q7S) is provided for cascading purposes.

Both the shift and storage register clocks are positive-edge triggered. If both clocks are connected together, the shift register is always one count pulse ahead of the storage register.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - ◆ Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Synchronous serial input and output
- Complies with JEDEC standard No.7A
- 8-bit parallel output
- Shift and storage registers have independent direct clear and clocks
- Independent clocks for shift and storage registers
- 100 MHz (typical)
- ESD protection:
 - ◆ MIL-STD-883, method 3015 exceeds 2000 V
 - ◆ HBM JESD22-A114F exceeds 2000 V
 - ♦ MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)

3. Applications

- Serial-to parallel data conversion
- Remote control holding register

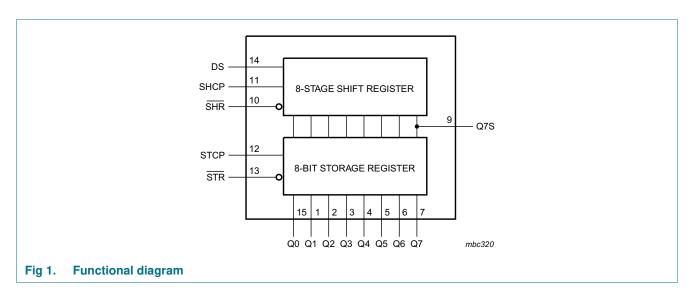


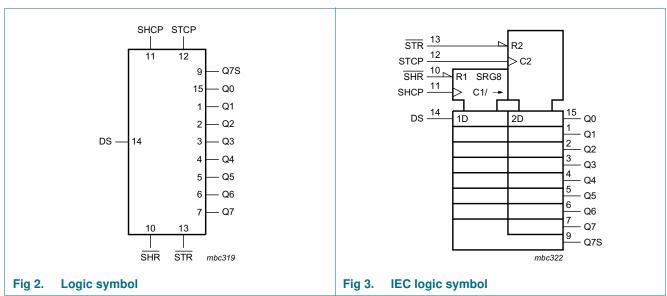
4. Ordering information

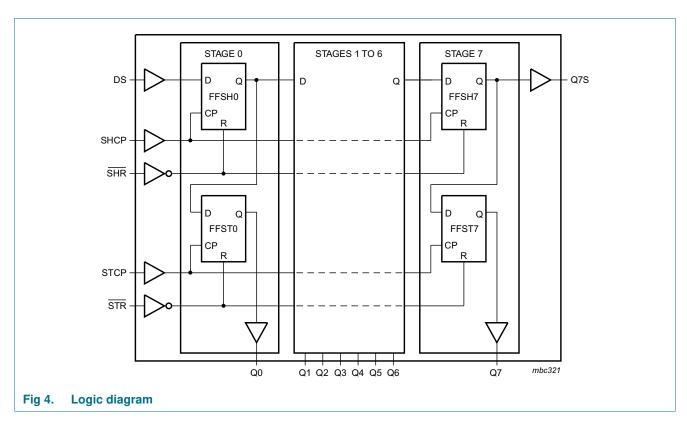
Table 1. Ordering information

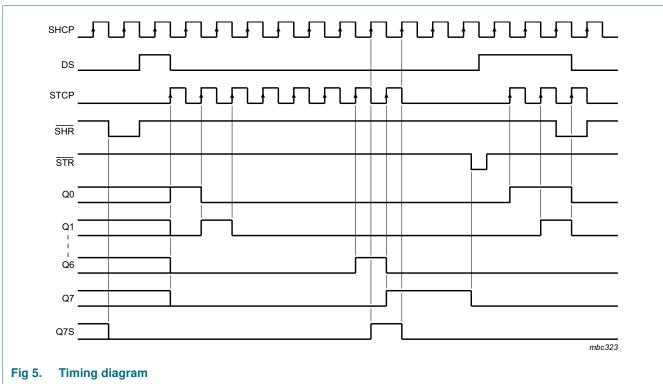
Type number	Package	Package						
	Temperature range	Name	Description	Version				
74HC594D-Q100	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads;	SOT109-1				
74HCT594D-Q100			body width 3.9 mm					
74HC594PW-Q100	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1				

5. Functional diagram



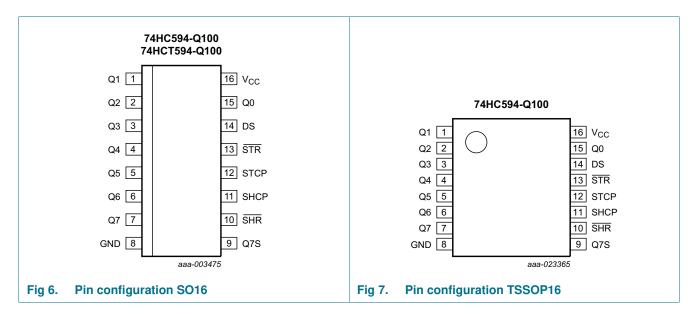






6. Pinning information

6.1 Pinning



6.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
Q0, Q1, Q2, Q3, Q4, Q5, Q6, Q7	15, 1, 2, 3, 4, 5, 6, 7	parallel data output
GND	8	ground (0 V)
Q7S	9	serial data output
SHR	10	shift register reset (active LOW)
SHCP	11	shift register clock input
STCP	12	storage register clock input
STR	13	storage register reset (active LOW)
DS	14	serial data input
V _{CC}	16	supply voltage

7. Functional description

Table 3. Function table[1]

Function	Input	X			
	SHR	STR	SHCP	STCP	DS
Clear shift register	L	Х	Х	Χ	Х
Clear storage register	Χ	L	Х	Χ	Х
Load DS into shift register stage 0, advance previous stage data to the next stage	Н	Х	\uparrow	Χ	H or L
Transfer shift register data to storage register and outputs Qn	Χ	Н	Х	↑	Х
Shift register one count pulse ahead of storage register	Н	Н	↑	↑	Х

^[1] H = HIGH voltage level; L = LOW voltage level; $L = LOW \text$

8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC}	supply voltage			-0.5	+7.0	V
I _{IK}	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$	[1]	-	±20	mA
I _{OK}	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$	[1]	-	±20	mA
Io	output current	$V_{O} = -0.5 \text{ V to } V_{CC} + 0.5 \text{ V}$				
		Serial data output Q7S		-	±25	mA
		Parallel data output		-	±35	mA
I _{CC}	supply current	Serial data output Q7S		-	50	mA
		Parallel data output		-	70	mA
I _{GND}	ground current	Serial data output Q7S		-	-50	mA
		Parallel data output		-	-70	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$	[2]	-	500	mW

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

^[2] For SO16 package: above 70 °C the value of P_{tot} derates linearly with 8 mW/K. For TSSOP16 package: P_{tot} derates linearly with 5.5 mW/K above 60 °C.

9. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Type 74HC	594-Q100					
V _{CC}	supply voltage		2.0	5.0	6.0	V
V _I	input voltage		0	-	V _{CC}	٧
Vo	output voltage		0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	°C
t _r	rise time	V _{CC} = 2.0 V	-	-	1000	ns
		$V_{CC} = 4.5 \text{ V}$	-	6.0	500	ns
		$V_{CC} = 6.0 \text{ V}$	-	-	400	ns
t _f	fall time	V _{CC} = 2.0 V	-	-	1000	ns
		$V_{CC} = 4.5 \text{ V}$	-	6.0	500	ns
		$V_{CC} = 6.0 \text{ V}$	-	-	400	ns
Type 74HC	CT594-Q100					
V _{CC}	supply voltage		4.5	5.0	5.5	V
VI	input voltage		0	-	V _{CC}	٧
Vo	output voltage		0	-	V _{CC}	٧
T _{amb}	ambient temperature		-40	+25	+125	°C
t _r	rise time	V _{CC} = 4.5 V	-	6.0	500	ns
t _f	fall time	V _{CC} = 4.5 V	-	6.0	500	ns

10. Static characteristics

Table 6. Static characteristics type 74HC594-Q100

Symbol	Parameter	Conditions	Min	Тур	Max	Unit				
T _{amb} = 25	°C									
V_{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	1.2	-	V				
	HIGH-level input voltage LOW-level input voltage	V _{CC} = 4.5 V	3.15	2.4	-	V				
		V _{CC} = 6.0 V	4.2	3.2	-	V				
V _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	0.8	0.5	V				
		V _{CC} = 4.5 V	-	2.1	1.35	V				
		V _{CC} = 6.0 V	-	2.8	1.8	V				
V _{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}								
		Serial data output Q7S								
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	4.32	-	V				
		$I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.48	5.81	-	V				
		Parallel data outputs			- 0.5 1.35 1.8					
		$I_{O} = -6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	4.32	-	V				
		$I_{O} = -7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.48	5.81	-	V				

Table 6. Static characteristics type 74HC594-Q100 ...continued

Symbol	Parameter	Conditions	Min	Тур	Max	Unit				
V _{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}								
		Serial data output Q7S	,	1						
		$I_O = 4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.15	0.26	V				
		I _O = 5.2 mA; V _{CC} = 6.0 V	-	0.16	0.26	V				
		Parallel data outputs	,	1						
		$I_{O} = 6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.15	0.26	V				
		$I_O = 7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.26	V				
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	μА				
I _{CC}	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 6.0 \text{ V}$	-	-	8.0	μΑ				
Ci	input capacitance		-	3.5	-	pF				
$T_{amb} = -40$	0 °C to +85 °C									
V_{IH}	HIGH-level input voltage		V							
		V _{CC} = 4.5 V	3.15	-	-	V				
		V _{CC} = 6.0 V	4.2	-	-	V				
V _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	-	0.5	V				
		V _{CC} = 4.5 V	-	-	1.35	V				
		$V_{CC} = 6.0 \text{ V}$	-	-	1.8	V				
V _{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}								
V _{OH}		Serial data output Q7S								
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.84	-	-	V				
		$I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.34	-	-	V				
		Parallel data outputs	·		 	·				
		$I_{O} = -6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.84	-	-	V				
		$I_{O} = -7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.34	-	-	V				
V _{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}			0.26 0.26 0.26 ±0.1 8.0 0.5 1.35 1.8 0.33 0.33					
		Serial data output Q7S	·			·				
		$I_O = 4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.33	V				
		$I_O = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	-	0.33	V				
		Parallel data outputs	·			·				
		$I_{O} = 6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.33	V				
		$I_{O} = 7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	-	0.33	V				
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±1.0	μΑ				
I _{CC}	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 6.0$ V	-	-	80	μА				

Table 6. Static characteristics type 74HC594-Q100 ...continued

Symbol	Parameter	Conditions	Min	Тур	Max	Unit			
T _{amb} = -4	0 °C to +125 °C			-	1				
V _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	-	-	V			
		V _{CC} = 4.5 V	3.15	-	-	V			
		$V_{CC} = 6.0 \text{ V}$	4.2	-	-	V			
V_{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	-	0.5	V			
		V _{CC} = 4.5 V	-	-	1.35	V			
		$V_{CC} = 6.0 \text{ V}$	-	-	- - - 0.5	V			
V _{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}							
		Serial data output Q7S	,	1					
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.7	-	-	V			
		$I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.2	-	-	V			
		Parallel data outputs							
		$I_{O} = -6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.7	-	-	V			
		$I_{O} = -7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.2	-	-	V			
V _{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}							
		Serial data output Q7S	,						
		$I_O = 4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.4	V			
		$I_O = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	-	0.4	V			
		Parallel data outputs	,						
		$I_{O} = 6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.4	V			
		$I_{O} = 7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	-	0.4	V			
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±1.0	μΑ			
I _{CC}	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 6.0$ V	-	-	160	μΑ			

Table 7. Static characteristics type 74HCT594-Q100

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 25	°C					
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	1.6	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	1.2	0.8	V
V _{OH}	HIGH-level output voltage	$V_{I} = V_{IH}$ or V_{IL}				
		Serial data output Q7S		1	1	
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	4.32	-	٧
		Parallel data outputs		1	1	
		$I_{O} = -6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	4.32	-	٧
V _{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		Serial data output Q7S		1	1	
		I _O = 4.0 mA; V _{CC} = 4.5 V	-	0.15	0.26	٧
		Parallel data outputs	1	2.0	1	
		I _O = 6.0 mA; V _{CC} = 4.5 V	-	0.16	0.26	٧
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±0.1	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	8.0	μА
Δl _{CC}	additional supply current	per input pin; $V_I = V_{CC} - 2.1 \text{ V}$ and other inputs at V_{CC} or GND; $I_O = 0 \text{ A}$; $V_{CC} = 4.5 \text{ V}$ to 5.5 V				
		pins SHR, SHCP, STCP, STR	-	150	540	μΑ
		pin DS	-	25	90	μΑ
Ci	input capacitance		-	3.5	-	pF
$T_{amb} = -40$	0 °C to +85 °C		·			
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	-	-	٧
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	-	8.0	٧
V _{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		Serial data output Q7S				
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.84	-	-	٧
		Parallel data outputs				
		$I_{O} = -6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.84	-	-	٧
V _{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		Serial data output	'			'
		I _O = 4.0 mA; V _{CC} = 4.5 V	-	-	0.33	V
		Parallel data outputs	1			1
		I _O = 6.0 mA; V _{CC} = 4.5 V	-	-	0.33	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±1.0	μА
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	80	μА

Table 7. Static characteristics type 74HCT594-Q100 ...continued

Symbol	Parameter	Conditions	Min	Тур	Max	Unit				
Δl _{CC}	additional supply current	per input pin; $V_I = V_{CC} - 2.1 \text{ V}$ and other inputs at V_{CC} or GND; $I_O = 0 \text{ A}$; $V_{CC} = 4.5 \text{ V}$ to 5.5 V								
		pins SHR, SHCP, STCP, STR	-	-	675	μΑ				
		pin DS	-	-	-	μΑ				
$T_{amb} = -40$	0 °C to +125 °C		,							
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	-	-	V				
V_{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	-	8.0	٧				
V _{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}								
		Serial data output Q7S								
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.7	-	-	V				
		Parallel data outputs		1						
		$I_{O} = -6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.7	-	-	٧				
V _{OL}	LOW-level output voltage $V_I = V_{IH}$ or V_{IL}									
/ _{OL}		Serial data output Q7S								
		I _O = 4.0 mA; V _{CC} = 4.5 V	-	-	0.4	V				
		Parallel data outputs								
		I _O = 6.0 mA; V _{CC} = 4.5 V	-	-	0.4	V				
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±1.0	μА				
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	160	μА				
Δl _{CC}	additional supply current	per input pin; $V_I = V_{CC} - 2.1 \text{ V}$ and other inputs at V_{CC} or GND; $I_O = 0 \text{ A}$; $V_{CC} = 4.5 \text{ V}$ to 5.5 V								
		pins SHR, SHCP, STCP, STR	-	-	735	μА				
		pin DS	-	-	122.5	μΑ				

11. Dynamic characteristics

Dynamic characteristics type 74HC594-Q100

 $GND = 0 \ V; t_r = t_f = 6 \ ns; C_L = 50 \ pF; see <u>Figure 14</u>.$

Symbol	Parameter	Conditions		25 °C		-40 °C to	o +85 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
t _{pd}	propagation d elay	SHCP to Q7S; [1] see Figure 8								
	-	V _{CC} = 2.0 V	-	44	150	-	185	-	225	ns
		V _{CC} = 4.5 V	-	16	30	-	37	-	45	ns
		V _{CC} = 5.0 V; C _L = 15 pF	-	13	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	14	26	-	31	-	38	ns
		STCP to Qn; see Figure 9								
		V _{CC} = 2.0 V	-	44	150	-	185	-	225	ns
		V _{CC} = 4.5 V	-	16	30	-	37	-	45	ns
		$V_{CC} = 5.0 \text{ V};$ $C_L = 15 \text{ pF}$	-	13	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	14	26	-	31	-	38	ns
t _{PHL} HIGH to LOW propagation	SHR to Q7S; see Figure 12									
	delay	V _{CC} = 2.0 V	-	39	150	-	185	-	225	ns
		V _{CC} = 4.5 V	-	14	30	-	37	-	45	ns
		$V_{CC} = 5.0 \text{ V};$ $C_L = 15 \text{ pF}$	-	11	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	12	26	-	31	-	38	ns
		STR to Qn; see Figure 13								
		$V_{CC} = 2.0 \text{ V}$	-	39	125	-	155	-	185	ns
		$V_{CC} = 4.5 \text{ V}$	-	14	25	-	31	-	37	ns
		$V_{CC} = 5.0 \text{ V};$ $C_L = 15 \text{ pF}$	-	11	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	12	21	-	26	-	31	ns
t _{THL}	HIGH to LOW	see Figure 8								
	output transition	Serial data output Q7S								
	time	$V_{CC} = 2.0 \text{ V}$	-	19	75	-	95	-	110	ns
		V _{CC} = 4.5 V	-	7	15	-	19	-	22	ns
		V _{CC} = 6.0 V	-	6	13	-	16	-	19	ns
		Parallel data outputs								
		V _{CC} = 2.0 V	-	14	60	-	75	-	90	ns
		V _{CC} = 4.5 V	-	5	12	-	15	-	18	ns
		$V_{CC} = 6.0 \text{ V}$	-	4	10	-	13	-	15	ns

Table 8. Dynamic characteristics type 74HC594-Q100 ...continued

 $GND = 0 \ V; t_r = t_f = 6 \ ns; C_L = 50 \ pF; see Figure 14.$

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
TLH	LOW to HIGH	see Figure 8								
	output transition	Serial data output Q7S						1		
	time	V _{CC} = 2.0 V	-	19	75	-	95	-	110	ns
		V _{CC} = 4.5 V	-	7	15	-	19	-	22	ns
		V _{CC} = 6.0 V	-	6	13	-	16	-	19	ns
		Parallel data outputs			1		-			
		V _{CC} = 2.0 V	-	14	60	-	75	-	90	ns
		V _{CC} = 4.5 V	-	5	12	-	15	-	18	ns
		V _{CC} = 6.0 V	-	4	10	-	13	-	15	ns
t _W pı	pulse width	SHCP (HIGH or LOW); see Figure 8								
		V _{CC} = 2.0 V	80	10	-	100	-	120	-	ns
		V _{CC} = 4.5 V	16	4	-	20	-	24	-	ns
		V _{CC} = 6.0 V	14	3	-	17	-	20	-	ns
		STCP (HIGH or LOW); see <u>Figure 9</u>								
		V _{CC} = 2.0 V	80	10	-	100	-	120	-	ns
		V _{CC} = 4.5 V	16	4	-	20	-	24	-	ns
		V _{CC} = 6.0 V	14	3	-	17	-	20	-	ns
		SHR and STR (HIGH or LOW); see Figure 12 and Figure 13								
		V _{CC} = 2.0 V	80	14	-	100	-	120	-	ns
		V _{CC} = 4.5 V	16	5	-	20	-	24	-	ns
		V _{CC} = 6.0 V	14	4	-	17	-	20	-	ns
su	set-up time	DS to SHCP; see Figure 10								
		V _{CC} = 2.0 V	100	10	-	125	-	150	-	ns
		V _{CC} = 4.5 V	20	4	-	25	-	30	-	ns
		V _{CC} = 6.0 V	17	3	-	21	-	26	-	ns
		SHR to STCP; see Figure 11								
		V _{CC} = 2.0 V	100	14	-	125	-	150	-	ns
		V _{CC} = 4.5 V	20	5	-	25	-	30	-	ns
		V _{CC} = 6.0 V	17	4	-	21	-	26	-	ns
		SHCP to STCP; see Figure 9								
		V _{CC} = 2.0 V	100	17	-	125	-	150	-	ns
		V _{CC} = 4.5 V	20	6	-	25	-	30	-	ns
		V _{CC} = 6.0 V	17	5	-	21	-	26	-	ns

 Table 8.
 Dynamic characteristics type 74HC594-Q100 ...continued

 $GND = 0 \ V; t_r = t_f = 6 \ ns; C_L = 50 \ pF; see <u>Figure 14</u>.$

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C to	Unit	
			Min	Тур	Max	Min	Max	Min	Max	
t _h	hold time	DS to SHCP; see Figure 10								
		V _{CC} = 2.0 V	25	-8	-	30	-	35	-	ns
		V _{CC} = 4.5 V	5	-3	-	6	-	7	-	ns
		V _{CC} = 6.0 V	4	-2	-	5	-	6	-	ns
t _{rec} recovery time	SHR to SHCP and STR to STCP; see Figure 12 and Figure 13									
		V _{CC} = 2.0 V	50	-14	-	65	-	75	-	ns
		V _{CC} = 4.5 V	10	-5	-	13	-	15	-	ns
		V _{CC} = 6.0 V	9	-4	-	11	-	13	-	ns
f _{max}	maximum frequency	SHCP or STCP; see Figure 8 and Figure 9								
		V _{CC} = 2.0 V	6.0	30	-	4.8	-	4.0	-	MHz
		V _{CC} = 4.5 V	30	92	-	24	-	20	-	MHz
		$V_{CC} = 5.0 \text{ V};$ $C_L = 15 \text{ pF}$	-	100	-	-	-	-	-	MHz
	V _{CC} = 6.0 V	35	109	-	28	-	24	-	MHz	
C_{PD}	power dissipation capacitance	$V_I = GND \text{ to } V_{CC};$ $V_{CC} = 5 \text{ V}; f_i = 1 \text{ MHz}$	-	84	-	-	-	-	-	pF

^[1] t_{pd} is the same as t_{PHL} and t_{PLH} .

[2] C_{PD} is used to determine the dynamic power dissipation (P_D in μW):

 $P_D = C_{PD} \times V_{CC}{}^2 \times f_i \times N + \sum (C_L \times V_{CC}{}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

Table 9. Dynamic characteristics type 74HCT594-Q100

 $GND = 0 \ V; \ V_{CC} = 4.5 \ V; \ t_r = t_f = 6 \ ns; \ C_L = 50 \ pF; \ see Figure 14.$

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C t	o +125 °C	Unit		
			Min	Тур	Max	Min	Max	Min	Max			
t _{pd}	propagation delay	SHCP to Q7S; [1] see Figure 8	-	18	32	-	40	-	48	ns		
		$V_{CC} = 5.0 \text{ V};$ $C_L = 15 \text{ pF}$	-	15	-	-	-	-	-	ns		
		STCP to Qn; see Figure 9	-	18	32	-	40	-	48	ns		
		$V_{CC} = 5.0 \text{ V};$ $C_L = 15 \text{ pF}$	-	15	-	-	-	-	-	ns		
t _{PHL}	HIGH to LOW propagation	SHR to Q7S; see Figure 12	-	17	30	-	38	-	45	ns		
	delay	$V_{CC} = 5.0 \text{ V};$ $C_L = 15 \text{ pF}$	-	14	-	-	-	-	-	ns		
	STR to Qn; see Figure 13	-	17	30	-	38	-	45	ns			
	$V_{CC} = 5.0 \text{ V};$ $C_L = 15 \text{ pF}$	-	14	-	-	-	-	-	ns			
t _{THL}	HIGH to LOW	see Figure 8										
	output transition time	Serial data output Q7S										
		$V_{CC} = 4.5 \text{ V}$	-	7	15	-	19	-	22	ns		
		Parallel data outputs										
		$V_{CC} = 4.5 \text{ V}$	-	5	12	-	15	-	18	ns		
t _{TLH}	LOW to HIGH	see Figure 8										
	output transition time	Serial data output Q7S										
	transition time	$V_{CC} = 4.5 \text{ V}$	-	7	15	-	19	-	22	ns		
		Parallel data outputs										
		$V_{CC} = 4.5 \text{ V}$	-	5	12	-	15	-	18	ns		
t _W	pulse width	SHCP (HIGH or LOW); see Figure 8	16	4	-	20	-	24	-	ns		
		STCP (HIGH or LOW); see <u>Figure 9</u>	16	4	-	20	-	24	-	ns		
	SHR and STR (HIGH or LOW); see Figure 12 and Figure 13	16	6	-	20	-	24	-	ns			
t _{su}	t _{su} set-up time	DS to SHCP; see <u>Figure 10</u>	20	4	-	25	-	30	-	ns		
		SHR to STCP; see Figure 11	20	6	-	25	-	30	-	ns		
		SHCP to STCP; see Figure 9	20	7	-	25	-	30	-	ns		
t _h	hold time	DS to SHCP; see Figure 10	5	-3	-	6	-	7	-	ns		

Table 9. Dynamic characteristics type 74HCT594-Q100 ...continued GND = 0 V; $V_{CC} = 4.5$ V; $t_r = t_f = 6$ ns; $C_L = 50$ pF; see Figure 14.

Symbol	Parameter	Conditions	25 °C			-40 °C t	o +85 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
t _{rec}	recovery time	SHR to SHCP and STR to STCP; see Figure 12 and Figure 13	10	-5	-	13	-	15	-	ns
f _{max}	maximum frequency	SHCP or STCP; see Figure 8 and Figure 9	30	92	-	24	-	20	-	MHz
		V _{CC} = 5.0 V; C _L = 15 pF	-	100	-	-	-	-	-	MHz
C _{PD}	power dissipation capacitance	$V_{I} = GND \text{ to } V_{CC} - $ [2] 1.5 V; $V_{CC} = 5 \text{ V}$; $f_{i} = 1 \text{ MHz}$	-	89	-	-	-	-	-	pF

[1] t_{pd} is the same as t_{PHL} and t_{PLH} .

[2] C_{PD} is used to determine the dynamic power dissipation (P_D in μW):

 $P_D = C_{PD} \times V_{CC}{}^2 \times f_i \times N + \sum (C_L \times V_{CC}{}^2 \times f_o)$ where:

f_i = input frequency in MHz;

fo = output frequency in MHz;

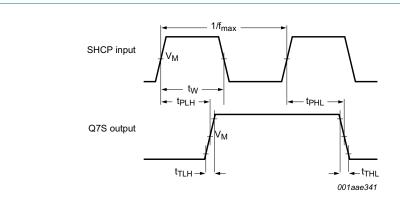
C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma (C_L \times V_{CC}^2 \times f_0) = sum of outputs.$

12. Waveforms

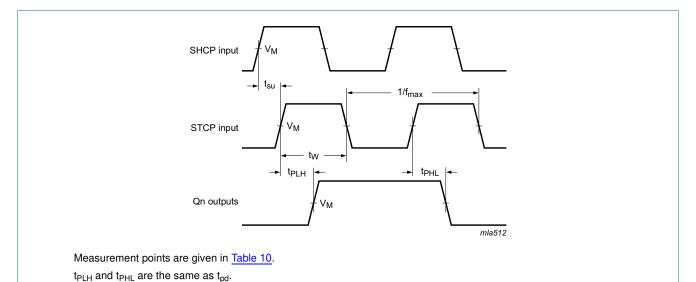


Measurement points are given in <u>Table 10</u>.

 t_{PLH} and t_{PHL} are the same as t_{pd} .

 t_{TLH} = LOW to HIGH output transition time; t_{THL} = HIGH to LOW output transition time.

Fig 8. The shift clock (SHCP) to output (Q7S) propagation delays, the shift clock pulse width, the maximum shift clock frequency, and output transition times



The storage clock (STCP) to output (Qn), propagation delays, the storage clock pulse width, the Fig 9. maximum storage clock pulse frequency and the shift clock to storage clock set-up time

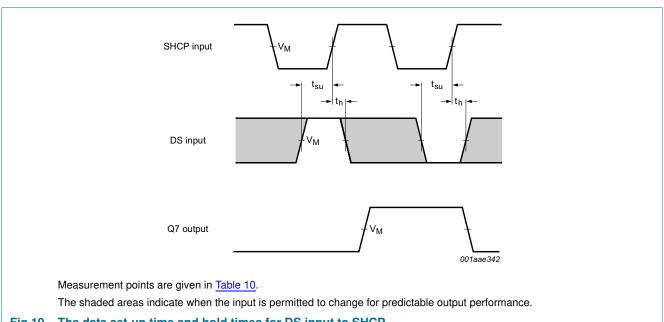
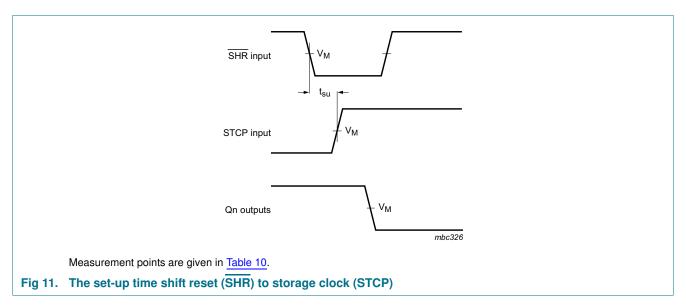
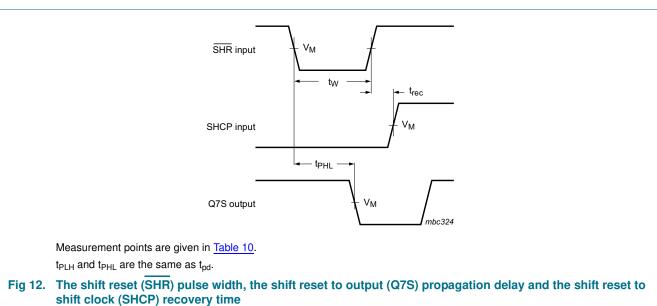
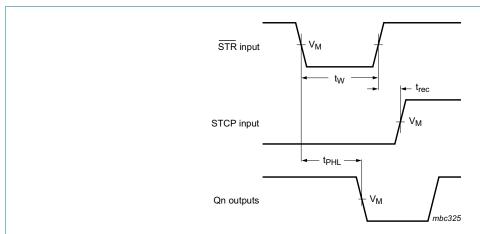


Fig 10. The data set-up time and hold times for DS input to SHCP





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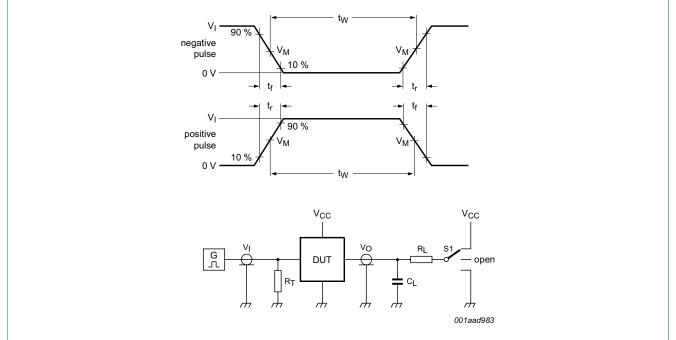
Measurement points are given in Table 10.

 t_{PLH} and t_{PHL} are the same as t_{pd} .

Fig 13. The storage reset (STR) pulse width, the storage reset to output (Qn) propagation delay and the storage reset to storage clock (STCP) recovery time

Table 10. Measurement points

Туре	Input	Output		
	V _M	V _M		
74HC594-Q100	0.5 × V _{CC}	$0.5 \times V_{CC}$		
74HCT594-Q100	1.3 V	1.3 V		



Test data is given in Table 11.

Definitions test circuit:

 R_T = Termination resistance should be equal to output impedance Z_0 of the pulse generator

C_L = Load capacitance including jig and probe capacitance

R_L = Load resistor

S1 = Test selection switch

Fig 14. Test circuit for measuring switching times

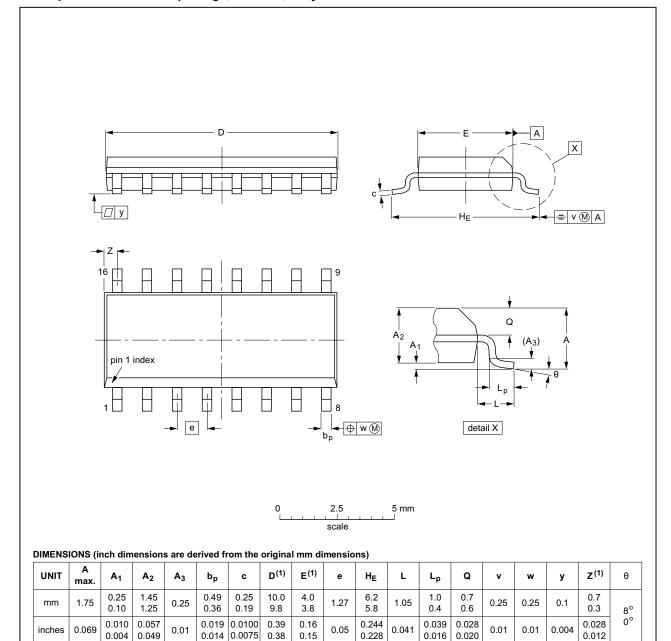
Table 11. Test data

Туре	Input		Load		S1 position			
	VI	t _r , t _f	CL	R _L	t _{PHL} , t _{PLH}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}	
74HC594-Q100	V _{CC}	6 ns	15 pF, 50 pF	1 kΩ	open	GND	V _{CC}	
74HCT594-Q100	3 V	6 ns	15 pF, 50 pF	1 kΩ	open	GND	V _{CC}	

13. Package outline

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT109-1	076E07	MS-012				99-12-27 03-02-19	

Fig 15. Package outline SOT109-1 (SO16)

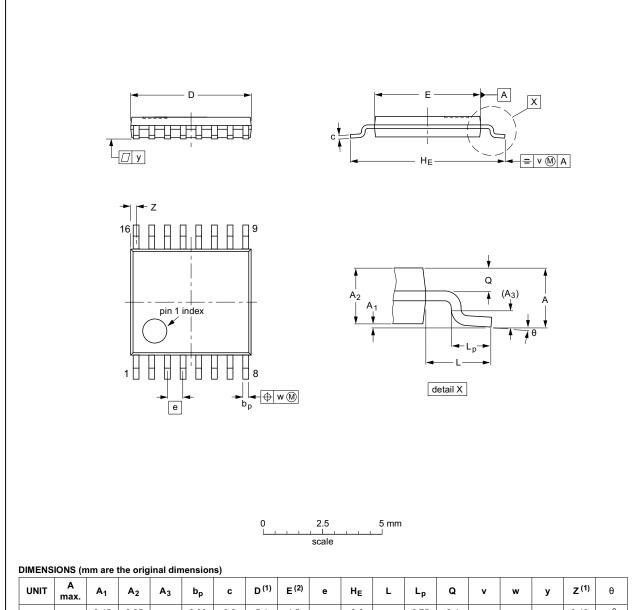
74HC_HCT594_Q100

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TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	C	D ⁽¹⁾	E ⁽²⁾	e	HE	L	Lp	Q	>	w	у	Z ⁽¹⁾	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.40 0.06	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT403-1		MO-153				99-12-27 03-02-18	

Fig 16. Package outline SOT403-1 (TSSOP16)

74HC_HCT594_Q100

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14. Abbreviations

Table 12. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
LSTTL	Low-Power Schottky Transistor-Transistor Logic
MM	Machine Model
TTL	Transistor-Transistor Logic

15. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
74HC_HCT594_Q100 v.2	20160613	Product data sheet	-	74HC_HCT594_Q100 v.1			
Modifications:	Added type number 74HC594PW-Q100 (SOT403-1).						
74HC_HCT594_Q100 v.1	20120802	Product data sheet	-	-			

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16. Legal information

16.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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74HC594-Q100; 74HCT594-Q100

Nexperia

8-bit shift register with output register

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